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Details

Product Status	Active
Core Processor	Coldfire V1
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	I ² C, SCI, SPI
Peripherals	LVD, PWM, WDT
Number of I/O	70
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 24x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcf51qe128clk

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1 MCF51QE128 Series Comparison

The following table compares the various device derivatives available within the MCF51QE128 series.

Table 1. MCF51QE128 Series Features by MCU and Package

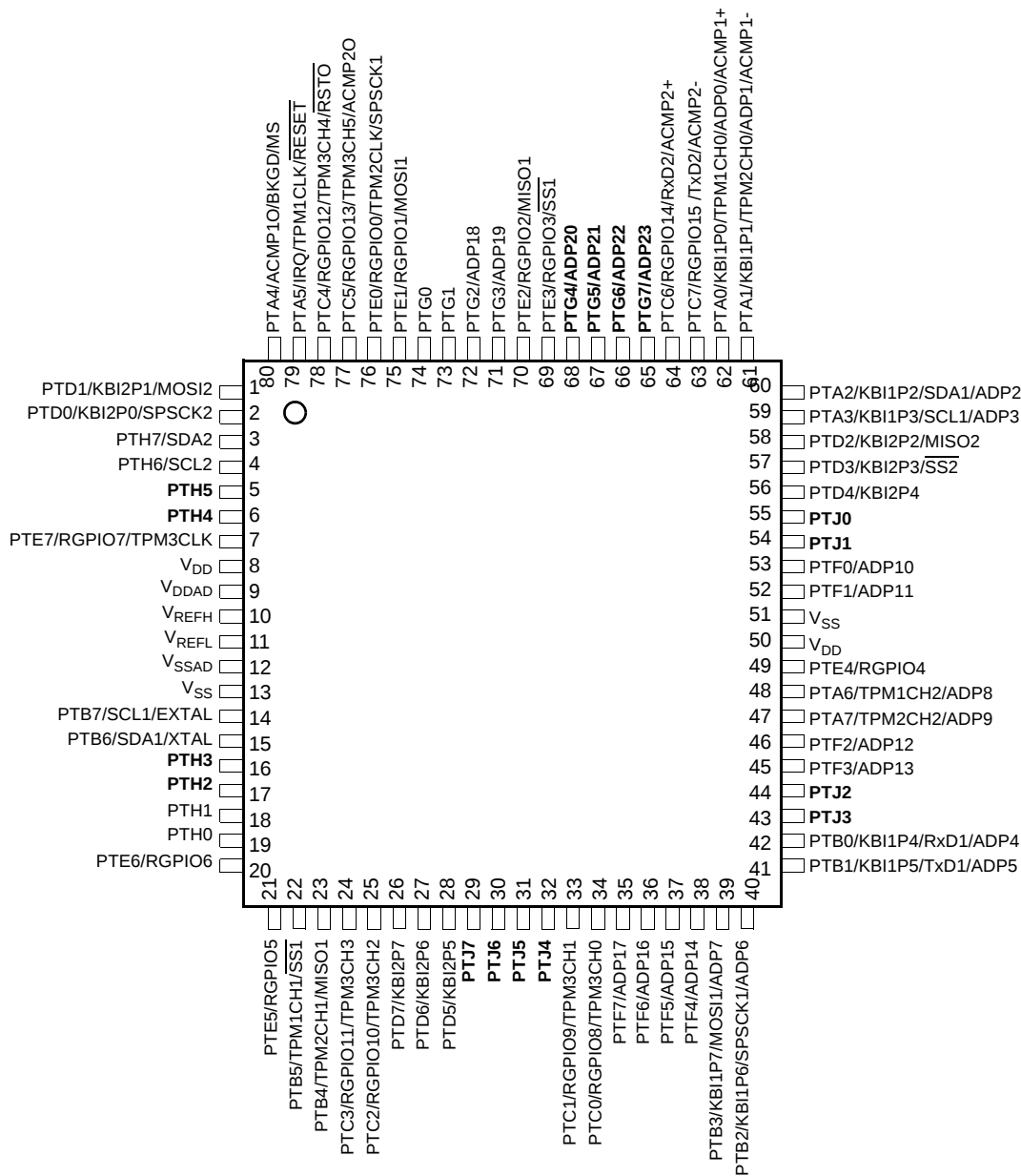
Feature	MCF51QE128		MCF51QE96		MCF51QE64	MCF51QE32
Flash size (bytes)	131072		98304		65536	32768
RAM size (bytes)	8192		8192		8192	8192
Pin quantity	80	64	80	64	64	64
Version 1 ColdFire core	yes					
ACMP1	yes					
ACMP2	yes					
ADC channels	24	20	24	20	20	20
DBG	yes					
ICS	yes					
IIC1	yes					
IIC2	yes					
KBI	16					
Port I/O ^{1, 2}	70	54	70	54	54	54
Rapid GPIO	yes					
RTC	yes					
SCI1	yes					
SCI2	yes					
SPI1	yes					
SPI2	yes					
External IRQ	yes					
TPM1 channels	3					
TPM2 channels	3					
TPM3 channels	6					
XOSC	yes					

¹ Port I/O count does not include the input-only PTA5/IRQ/TPM1CLK/RESET or the output-only PTA4/ACMP1O/BKGD/MS.

² 16 bits associated with Ports C and E are shadowed with ColdFire Rapid GPIO module.

2 Pin Assignments

This section describes the pin assignments for the available packages. See [Table 1](#) for pin availability by package pin-count.



Pins in **bold** are added from the next smaller package.

Figure 2. Pin Assignments in 80-Pin LQFP

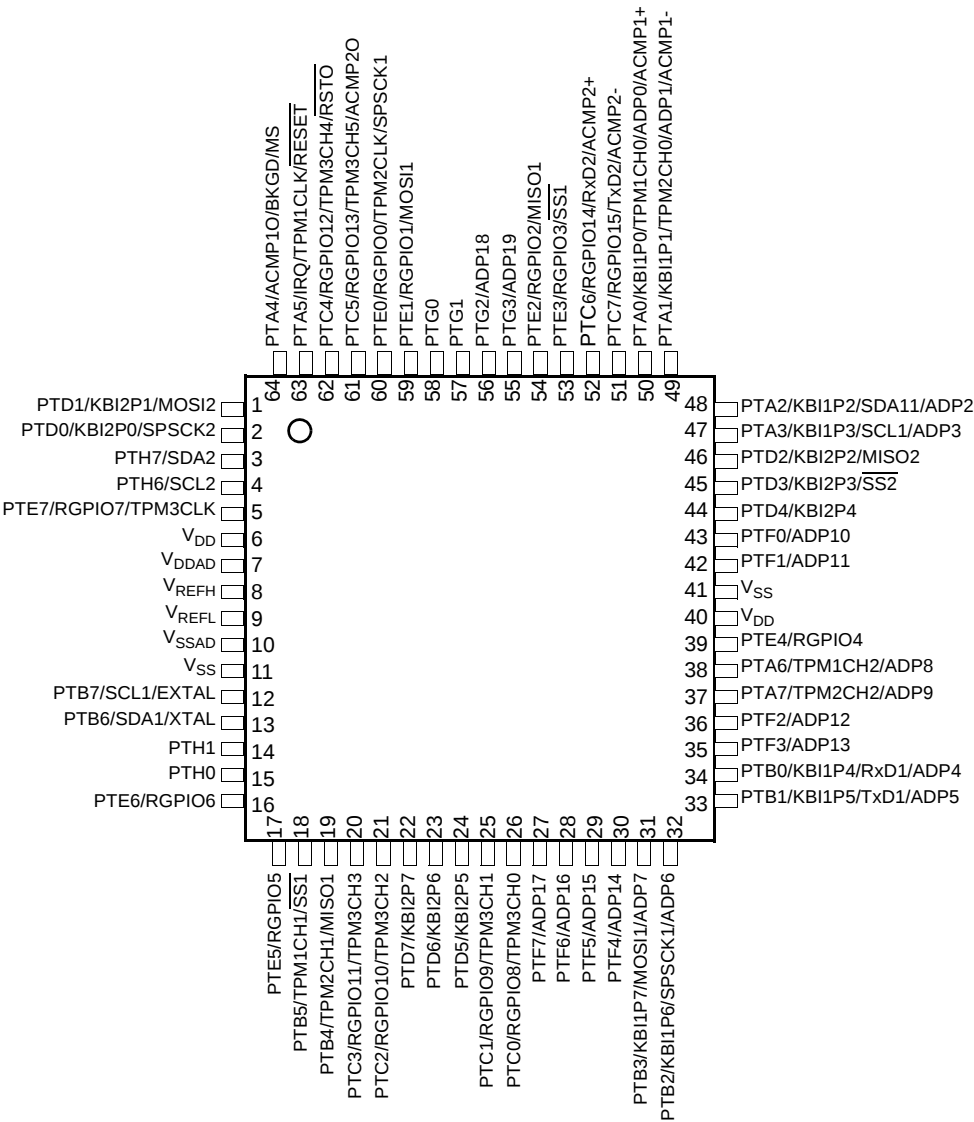


Figure 3. Pin Assignments in 64-Pin LQFP Package

Table 2. MCF51QE128 Series Pin Assignment by Package and Pin Sharing Priority

Pin Number		Lowest	←	Priority	→	Highest
80	64	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
1	1	PTD1	KBI2P1	MOSI2		
2	2	PTD0	KBI2P0	SPSCK2		
3	3	PTH7	SDA2			
4	4	PTH6	SCL2			
5	—	PTH5				
6	—	PTH4				
7	5	PTE7	RGPIO7	TPM3CLK		
8	6					V _{DD}
9	7					V _{DDAD}
10	8					V _{REFH}
11	9					V _{REFL}
12	10					V _{SSAD}
13	11					V _{SS}
14	12	PTB7	SCL1			EXTAL
15	13	PTB6	SDA1			XTAL
16	—	PTH3				
17	—	PTH2				
18	14	PTH1				
19	15	PTH0				
20	16	PTE6	RGPIO6			
21	17	PTE5	RGPIO5			
22	18	PTB5	TPM1CH1	SS1		
23	19	PTB4	TPM2CH1	MISO1		
24	20	PTC3	RGPIO11	TPM3CH3		
25	21	PTC2	RGPIO10	TPM3CH2		
26	22	PTD7	KBI2P7			
27	23	PTD6	KBI2P6			
28	24	PTD5	KBI2P5			
29	—	PTJ7				
30	—	PTJ6				
31	—	PTJ5				
32	—	PTJ4				
33	25	PTC1	RGPIO9	TPM3CH1		
34	26	PTC0	RGPIO8	TPM3CH0		
35	27	PTF7				ADP17
36	28	PTF6				ADP16
37	29	PTF5				ADP15
38	30	PTF4				ADP14
39	31	PTB3	KBI1P7	MOSI1 ¹		ADP7
40	32	PTB2	KBI1P6	SPSCK1		ADP6

Table 7. ESD and Latch-Up Protection Characteristics

No.	Rating ¹	Symbol	Min	Max	Unit
1	Human body model (HBM)	V_{HBM}	± 2000	—	V
2	Machine model (MM)	V_{MM}	± 200	—	V
3	Charge device model (CDM)	V_{CDM}	± 500	—	V
4	Latch-up current at $T_A = 85^\circ\text{C}$	I_{LAT}	± 100	—	mA

¹ Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

3.6 DC Characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 8. DC Characteristics

Num	C	Characteristic	Symbol	Condition	Min	Typ ¹	Max	Unit	
1		Operating Voltage			1.8 ²		3.6	V	
2	C	Output high voltage All I/O pins, low-drive strength	V _{OH}	1.8 V, I _{Load} = −2 mA	V _{DD} − 0.5	—	—	V	
	P	All I/O pins, high-drive strength		2.7 V, I _{Load} = −10 mA	V _{DD} − 0.5	—	—		
	T	2.3 V, I _{Load} = −6 mA		V _{DD} − 0.5	—	—			
	C	1.8V, I _{Load} = −3 mA		V _{DD} − 0.5	—	—			
3	D	Output high current Max total I _{OH} for all ports	I _{OHT}		—	—	100	mA	
4	C	Output low voltage All I/O pins, low-drive strength	V _{OL}	1.8 V, I _{Load} = 2 mA	—	—	0.5	V	
	P	All I/O pins, high-drive strength		2.7 V, I _{Load} = 10 mA	—	—	0.5		
	T	2.3 V, I _{Load} = 6 mA		—	—	0.5			
	C	1.8 V, I _{Load} = 3 mA		—	—	0.5			
5	D	Output low current Max total I _{OL} for all ports	I _{OLT}		—	—	100	mA	
6	P	Input high voltage all digital inputs	V _{IH}	V _{DD} > 2.7 V	0.70 x V _{DD}	—	—	V	
	C	V _{DD} > 1.8 V		0.85 x V _{DD}	—	—			
7	P	Input low voltage all digital inputs	V _{IL}	V _{DD} > 2.7 V	—	—	0.35 x V _{DD}		
	C	V _{DD} >1.8 V		—	—	0.30 x V _{DD}			
8	C	Input hysteresis all digital inputs	V _{hys}		0.06 x V _{DD}	—	—	mV	
9	P	Input leakage current all input only pins (Per pin)	I _{In}	V _{In} = V _{DD} or V _{SS}	—	—	1	μA	
10	P	Hi-Z (off-state) leakage current all input/output (per pin)	I _{OZ}	V _{In} = V _{DD} or V _{SS}	—	—	1	μA	
11	P	Pull-up resistors all digital inputs, when enabled	R _{PU}		17.5	—	52.5	kΩ	

Table 8. DC Characteristics (continued)

Num	C	Characteristic	Symbol	Condition	Min	Typ ¹	Max	Unit
12	D	DC injection current ^{3, 4, 5}	I_{IC}	$V_{IN} < V_{SS}, V_{IN} > V_{DD}$	-0.2	—	0.2	mA
		Single pin limit Total MCU limit, includes sum of all stressed pins			-5	—	5	mA
13	C	Input Capacitance, all pins	C_{In}		—	—	8	pF
14	C	RAM retention voltage	V_{RAM}		—	0.6	1.0	V
15	C	POR re-arm voltage ⁶	V_{POR}		0.9	1.4	1.79	V
16	D	POR re-arm time	t_{POR}		10	—	—	μs
17	P	Low-voltage detection threshold — high range ⁷	V_{LVDH} ⁸	V_{DD} falling V_{DD} rising	2.11 2.16	2.16 2.21	2.22 2.27	V
18	P	Low-voltage detection threshold — low range ⁷	V_{LVDL}	V_{DD} falling V_{DD} rising	1.80 1.86	1.82 1.90	1.91 1.99	V
19	P	Low-voltage warning threshold — high range ⁷	V_{LVWH}	V_{DD} falling V_{DD} rising	2.36 2.36	2.46 2.46	2.56 2.56	V
20	P	Low-voltage warning threshold — low range ⁷	V_{LVWL}	V_{DD} falling V_{DD} rising	2.11 2.16	2.16 2.21	2.22 2.27	V
21	C	Low-voltage inhibit reset/recover hysteresis ⁷	V_{hys}		—	50	—	mV
22	P	Bandgap Voltage Reference ⁹	V_{BG}		1.15	1.17	1.18	V

¹ Typical values are measured at 25°C. Characterized, not tested

² As the supply voltage rises, the LVD circuit will hold the MCU in reset until the supply has risen above V_{LVDL} .

³ All functional non-supply pins are internally clamped to V_{SS} and V_{DD} .

⁴ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

⁵ Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{IN} > V_{DD}$) is greater than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if clock rate is very low (which would reduce overall power consumption).

⁶ Maximum is highest voltage that POR is guaranteed.

⁷ Low voltage detection and warning limits measured at 1 MHz bus frequency.

⁸ Run at 1 MHz bus frequency

⁹ Factory trimmed at $V_{DD} = 3.0$ V, Temp = 25°C

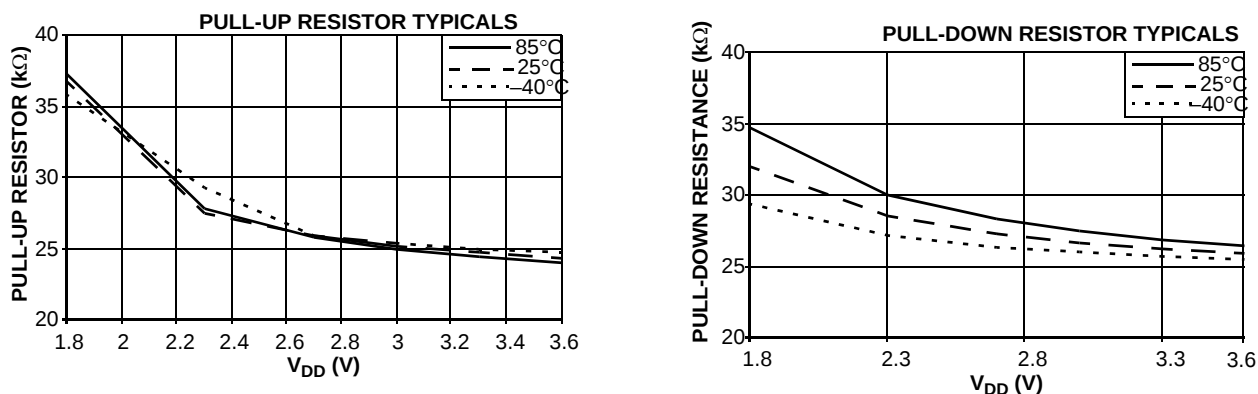


Figure 4. Pull-up and Pull-down Typical Resistor Values

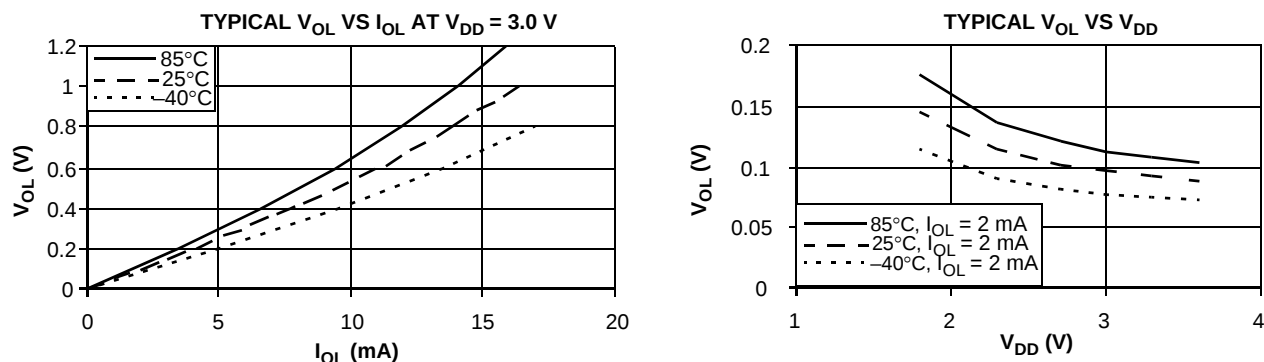


Figure 5. Typical Low-Side Driver (Sink) Characteristics — Low Drive (PTxDSn = 0)

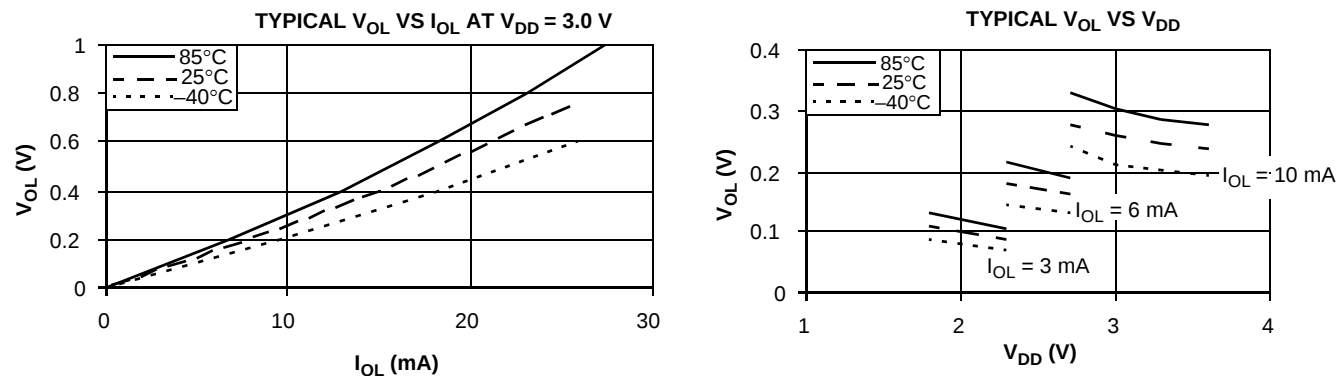


Figure 6. Typical Low-Side Driver (Sink) Characteristics — High Drive (PTxDSn = 1)

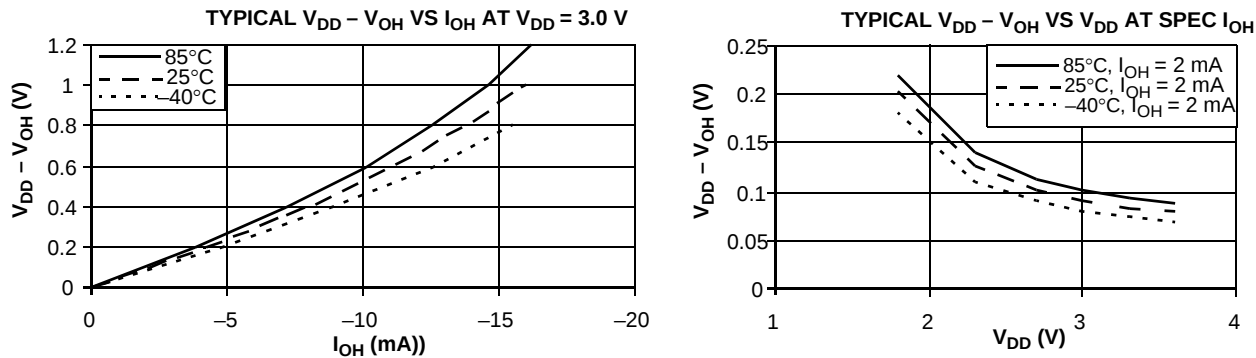


Figure 7. Typical High-Side (Source) Characteristics — Low Drive (PTxDSn = 0)

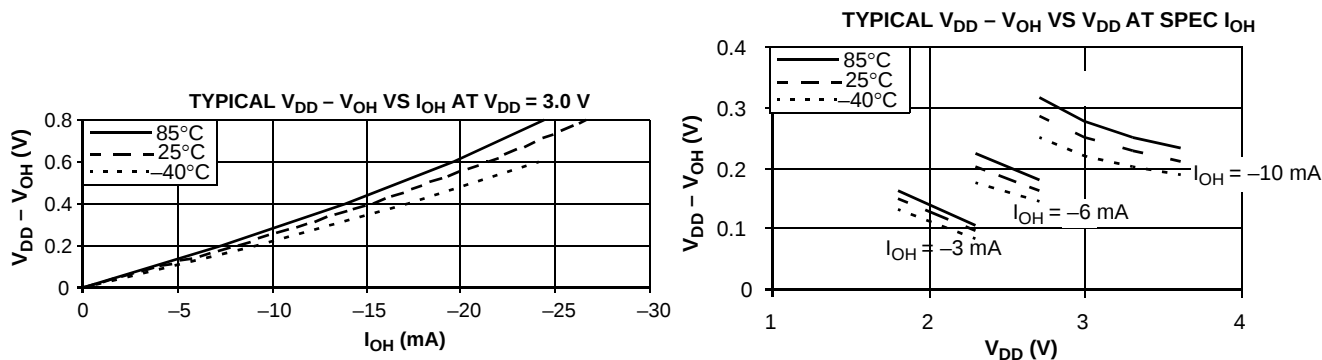


Figure 8. Typical High-Side (Source) Characteristics — High Drive (PTxDSn = 1)

3.7 Supply Current Characteristics

This section includes information about power supply current in various operating modes.

Table 9. Supply Current Characteristics

Num	C	Parameter	Symbol	Bus Freq	V_{DD} (V)	Typ ¹	Max	Unit	Temp (°C)
1	P	Run supply current FEI mode, all modules on	$R_{I_{DD}}$	25.165 MHz	3	32	35	mA	-40 to 25
	P					32	35		85
	T					28.0	—		-40 to 85
	T					13.2	—		
	T					2.4	—		
2	C	Run supply current FEI mode, all modules off	$R_{I_{DD}}$	25.165 MHz	3	28.1	29.6	mA	-40 to 85
	T			20 MHz		22.9	—		
	T			8 MHz		11.3	—		
	T			1 MHz		2.0	—		

Table 12. ICS Frequency Specifications (Temperature Range = -40 to 85°C Ambient) (continued)

Num	C	Characteristic	Symbol	Min	Typ ¹	Max	Unit
8	C	Total deviation of trimmed DCO output frequency over voltage and temperature	$\Delta f_{\text{dco_t}}$	—	+ 0.5 -1.0	± 2	%f _{dco}
9	C	Total deviation of trimmed DCO output frequency over fixed voltage and temperature range of 0°C to 70 °C	$\Delta f_{\text{dco_t}}$	—	± 0.5	± 1	%f _{dco}
10	C	FLL acquisition time ³	t _{Acquire}	—	—	1	ms
11	C	Long term jitter of DCO output clock (averaged over 2-ms interval) ⁴	C _{Jitter}	—	0.02	0.2	%f _{dco}

¹ Data in Typical column was characterized at 3.0 V, 25°C or is typical recommended value.

² The resulting bus clock frequency should not exceed the maximum specified bus clock frequency of the device.

³ This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

⁴ Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{Bus}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V_{DD} and V_{SS} and variation in crystal oscillator frequency increase the C_{Jitter} percentage for a given interval.

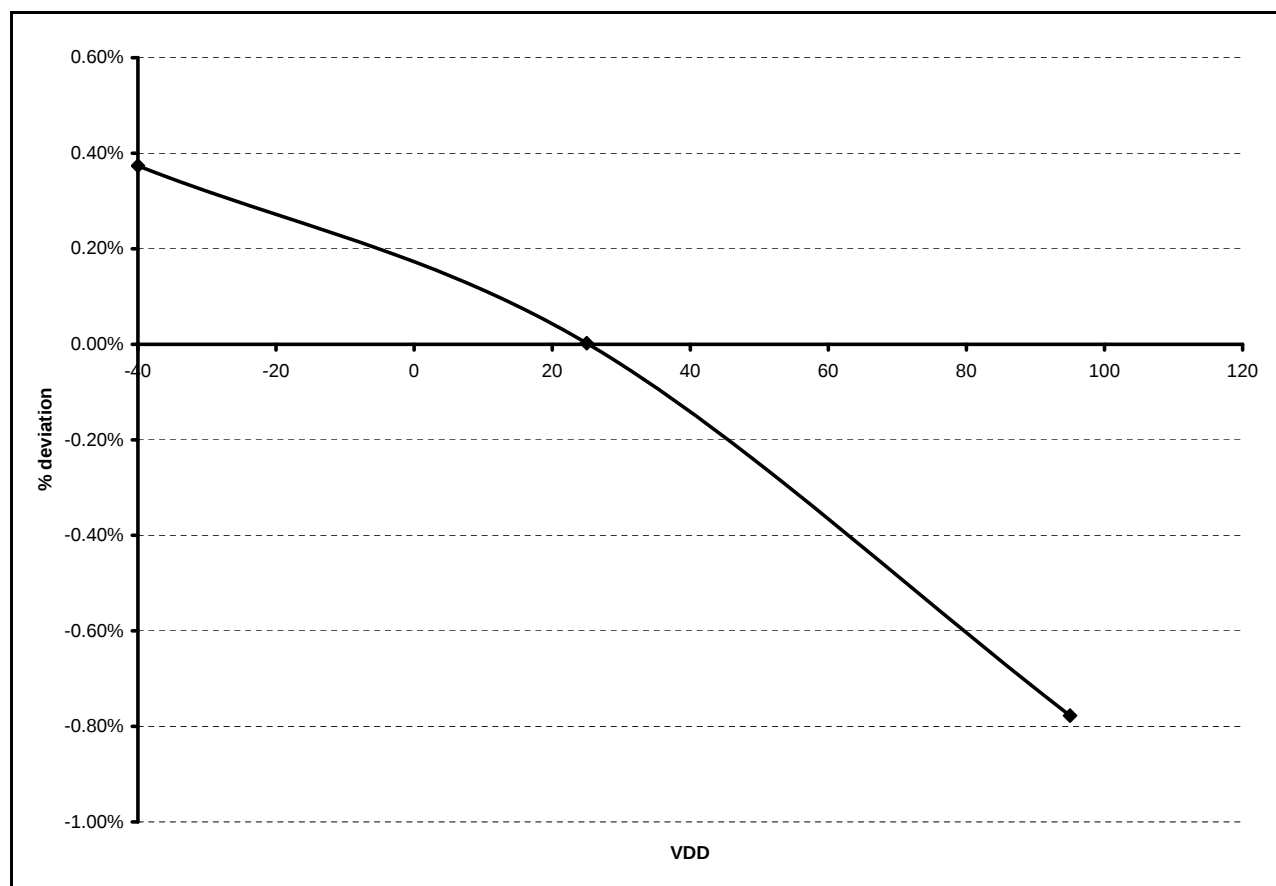
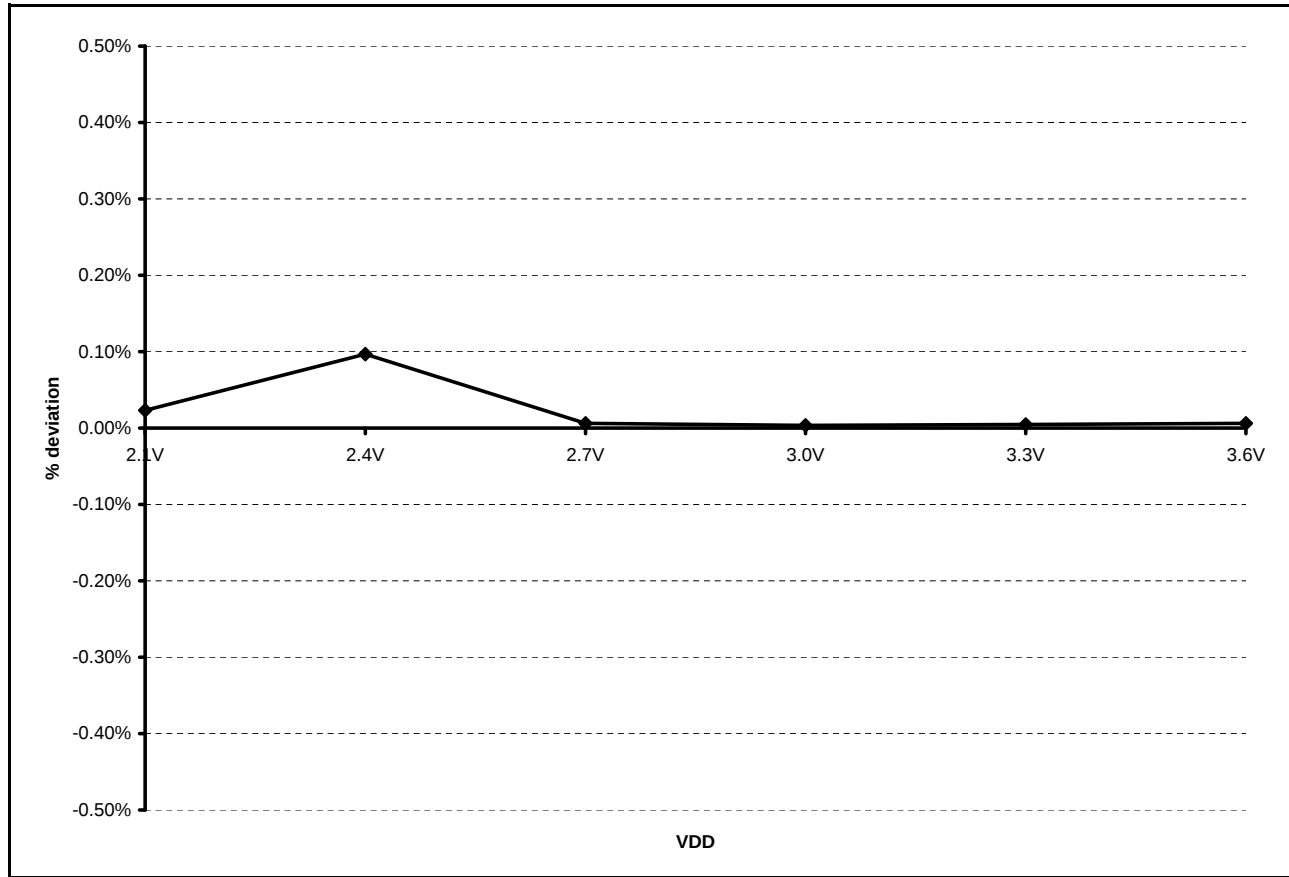


Figure 12. Deviation of DCO Output Across Temperature at V_{DD} = 3.0 V


Figure 13. Deviation of DCO Output Across V_{DD} at 25°C

3.10 AC Characteristics

This section describes timing characteristics for each peripheral system.

3.10.1 Control Timing

Table 13. Control Timing

Num	C	Rating	Symbol	Min	Typ ¹	Max	Unit
1	D	Bus frequency ($t_{cyc} = 1/f_{Bus}$) $V_{DD} \geq 1.8V$ $V_{DD} > 2.1V$ $V_{DD} > 2.4V$	f_{Bus}	dc	— — —	10 20 25.165	MHz
2	D	Internal low power oscillator period	t_{LPO}	700	—	1300	μs
3	D	External reset pulse width ²	t_{extrst}	100	—	—	ns
4	D	Reset low drive	t_{rstdrv}	$34 \times t_{cyc}$	—	—	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes	t_{MSSU}	500	—	—	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes ³	t_{MSH}	100	—	—	μs

Table 13. Control Timing (continued)

Num	C	Rating	Symbol	Min	Typ ¹	Max	Unit
7	D	IRQ pulse width Asynchronous path ² Synchronous path ⁴	$t_{\text{LIH}}, t_{\text{HIL}}$	100 $2 \times t_{\text{cyc}}$	— —	— —	ns
8	D	Keyboard interrupt pulse width Asynchronous path ² Synchronous path ⁴	$t_{\text{LIH}}, t_{\text{HIL}}$	100 $2 \times t_{\text{cyc}}$	— —	— —	ns
9	C	Port rise and fall time — Low output drive (PTxDS = 0) (load = 50 pF) ⁵ Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	$t_{\text{Rise}}, t_{\text{Fall}}$	— —	8 31	— —	ns
		Port rise and fall time — High output drive (PTxDS = 1) (load = 50 pF) Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	$t_{\text{Rise}}, t_{\text{Fall}}$	— —	7 24	— —	ns
10		Voltage regulator recovery time	t_{VRR}	—	4	—	μs

¹ Typical values are based on characterization data at $V_{\text{DD}} = 3.0\text{V}$, 25°C unless otherwise stated.

² This is the shortest pulse that is guaranteed to be recognized as a reset or interrupt pin request. Shorter pulses are not guaranteed to override reset requests from internal sources.

³ To enter BDM mode following a POR, BKGD/MS should be held low during the power-up and for a hold time of t_{MSH} after V_{DD} rises above V_{LVD} .

⁴ This is the minimum assertion time in which the interrupt **may** be recognized. The correct protocol is to assert the interrupt request until it is explicitly negated by the interrupt service routine.

⁵ Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range -40°C to 85°C .

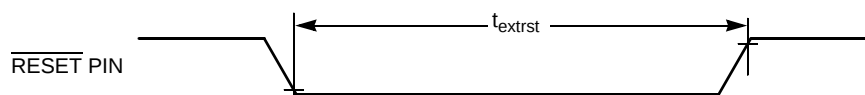


Figure 14. Reset Timing

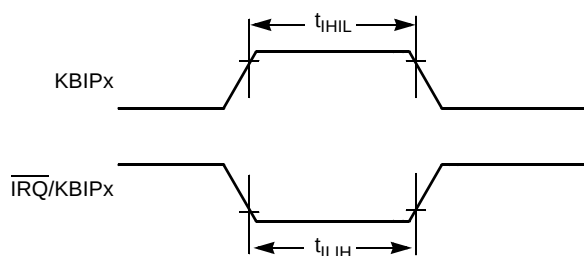


Figure 15. $\overline{\text{IRQ}}/\text{KBIPx}$ Timing

3.10.2 TPM Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 14. TPM Input Timing

No.	C	Function	Symbol	Min	Max	Unit
1	D	External clock frequency	f_{TCLK}	0	$f_{Bus}/4$	Hz
2	D	External clock period	t_{TCLK}	4	—	t_{cyc}
3	D	External clock high time	t_{clkh}	1.5	—	t_{cyc}
4	D	External clock low time	t_{clkl}	1.5	—	t_{cyc}
5	D	Input capture pulse width	t_{ICPW}	1.5	—	t_{cyc}

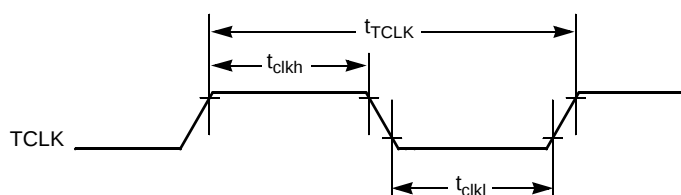


Figure 16. Timer External Clock

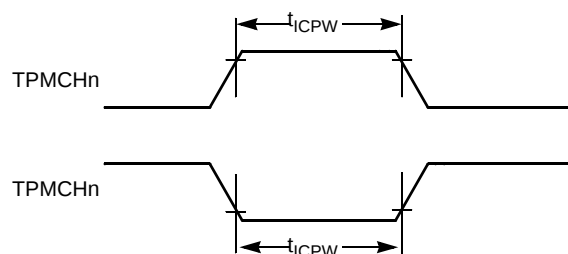


Figure 17. Timer Input Capture Pulse

3.10.3 SPI Timing

Table 15 and Figure 18 through Figure 21 describe the timing requirements for the SPI system.

Table 15. SPI Timing

No.	C	Function	Symbol	Min	Max	Unit
—	D	Operating frequency Master Slave	f_{op}	$f_{BUS}/2048$ 0	$f_{BUS}/2$ $f_{BUS}/4$	Hz Hz
1	D	SPSCK period Master Slave	t_{SPSCK}	2 4	2048 —	t_{cyc} t_{cyc}
2	D	Enable lead time Master Slave	t_{Lead}	1/2 1	— —	t_{SPSCK} t_{cyc}
3	D	Enable lag time Master Slave	t_{Lag}	1/2 1	— —	t_{SPSCK} t_{cyc}
4	D	Clock (SPSCK) high or low time Master Slave	t_{WSPSCK}	$t_{cyc} - 30$ $t_{cyc} - 30$	$1024 t_{cyc}$ —	ns ns
5	D	Data setup time (inputs) Master Slave	t_{SU}	15 15	— —	ns ns
6	D	Data hold time (inputs) Master Slave	t_{HI}	0 25	— —	ns ns
7	D	Slave access time	t_a	—	1	t_{cyc}
8	D	Slave MISO disable time	t_{dis}	—	1	t_{cyc}
9	D	Data valid (after SPSCK edge) Master Slave	t_v	— —	25 25	ns ns
10	D	Data hold time (outputs) Master Slave	t_{HO}	0 0	— —	ns ns
11	D	Rise time Input Output	t_{RI} t_{RO}	— —	$t_{cyc} - 25$ 25	ns ns
12	D	Fall time Input Output	t_{FI} t_{FO}	— —	$t_{cyc} - 25$ 25	ns ns

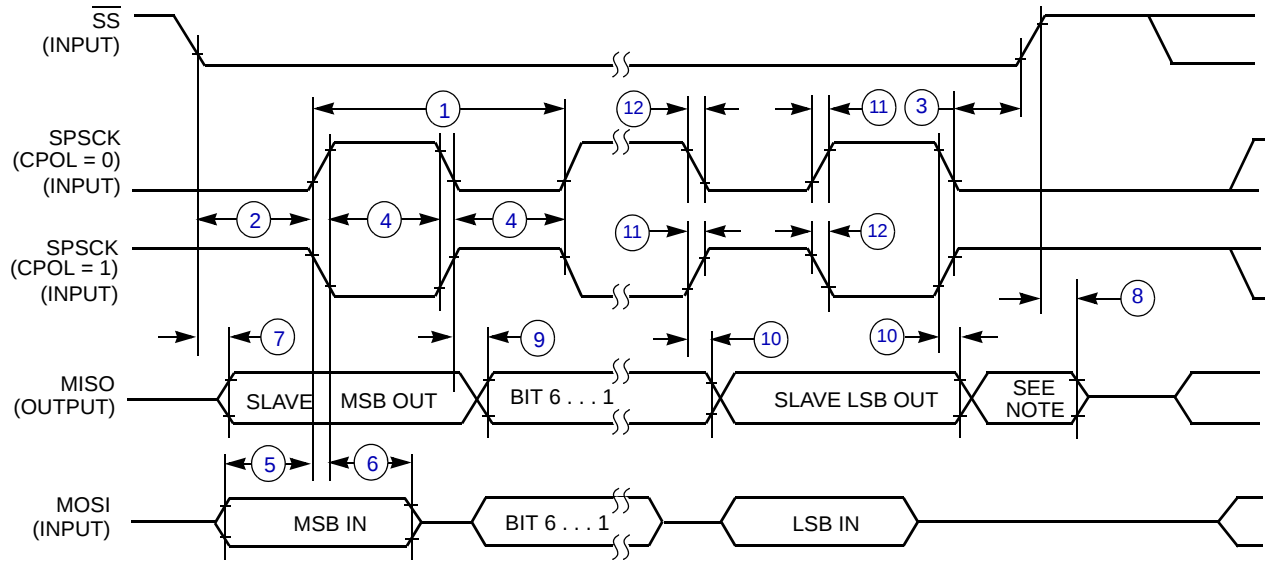


Figure 20. SPI Slave Timing (CPHA = 0)

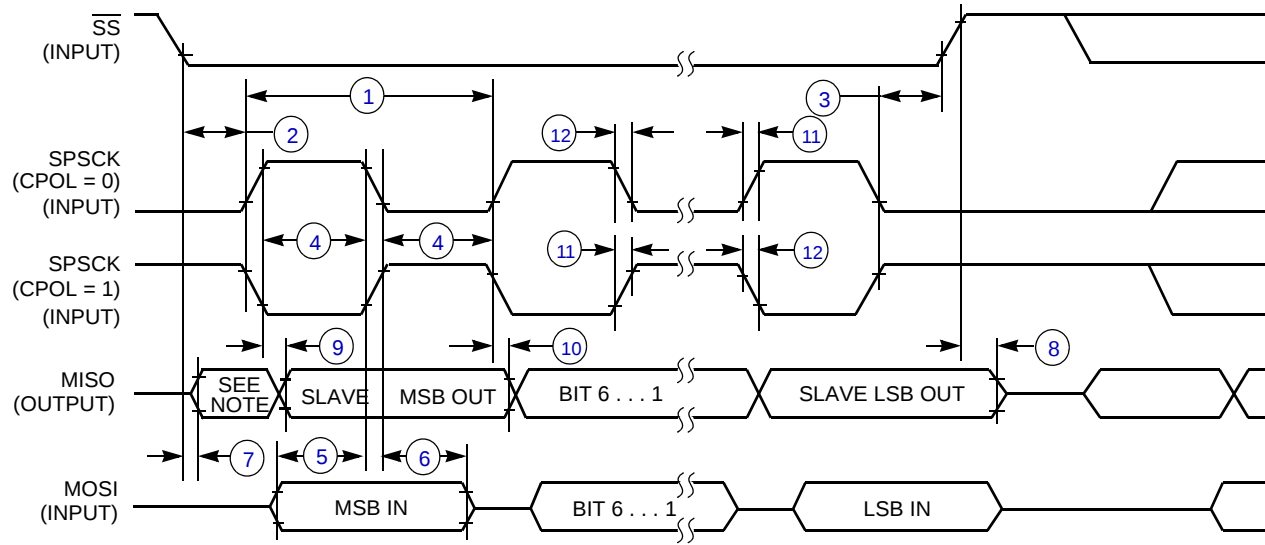


Figure 21. SPI Slave Timing (CPHA = 1)

3.11 Analog Comparator (ACMP) Electricals

Table 16. Analog Comparator Electrical Specifications

C	Characteristic	Symbol	Min	Typical	Max	Unit
D	Supply voltage	V_{DD}	1.80	—	3.6	V
C	Supply current (active)	I_{DDAC}	—	20	35	μA
D	Analog input voltage	V_{AIN}	$V_{SS} - 0.3$	—	V_{DD}	V
C	Analog input offset voltage	V_{AIO}		20	40	mV
C	Analog comparator hysteresis	V_H	3.0	9.0	15.0	mV
P	Analog input leakage current	I_{ALKG}	—	—	1.0	μA
C	Analog comparator initialization delay	t_{AINIT}	—	—	1.0	μs

3.12 ADC Characteristics

Table 17. 12-bit ADC Operating Conditions

C	Characteristic	Conditions	Symb	Min	Typ ¹	Max	Unit	Comment
D	Supply voltage	Absolute	V_{DDAD}	1.8	—	3.6	V	
		Delta to V_{DD} ($V_{DD} - V_{DDAD}$) ²	ΔV_{DDAD}	-100	0	+100	mV	
D	Ground voltage	Delta to V_{SS} ($V_{SS} - V_{SSAD}$) ²	ΔV_{SSAD}	-100	0	+100	mV	
D	Ref Voltage High		V_{REFH}	1.8	V_{DDAD}	V_{DDAD}	V	
D	Ref Voltage Low		V_{REFL}	V_{SSAD}	V_{SSAD}	V_{SSAD}	V	
D	Input Voltage		V_{ADIN}	V_{REFL}	—	V_{REFH}	V	
C	Input Capacitance		C_{ADIN}	—	4.5	5.5	pF	
C	Input Resistance		R_{ADIN}	—	5	7	k Ω	
C	Analog Source Resistance	12 bit mode $f_{ADCK} > 4\text{MHz}$ $f_{ADCK} < 4\text{MHz}$	R_{AS}	— —	— —	2 5	k Ω	External to MCU
		10 bit mode $f_{ADCK} > 4\text{MHz}$ $f_{ADCK} < 4\text{MHz}$		— —	— —	5 10		
		8 bit mode (all valid f_{ADCK})		—	—	10		
D	ADC Conversion Clock Freq.	High Speed (ADLPC=0)	f_{ADCK}	0.4	—	8.0	MHz	
		Low Power (ADLPC=1)		0.4	—	4.0		

¹ Typical values assume $V_{DDAD} = 3.0V$, Temp = 25°C, $f_{ADCK} = 1.0\text{MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² DC potential difference.

Table 18. 12-bit ADC Characteristics ($V_{REFH} = V_{DDAD}$, $V_{REFL} = V_{SSAD}$) (continued)

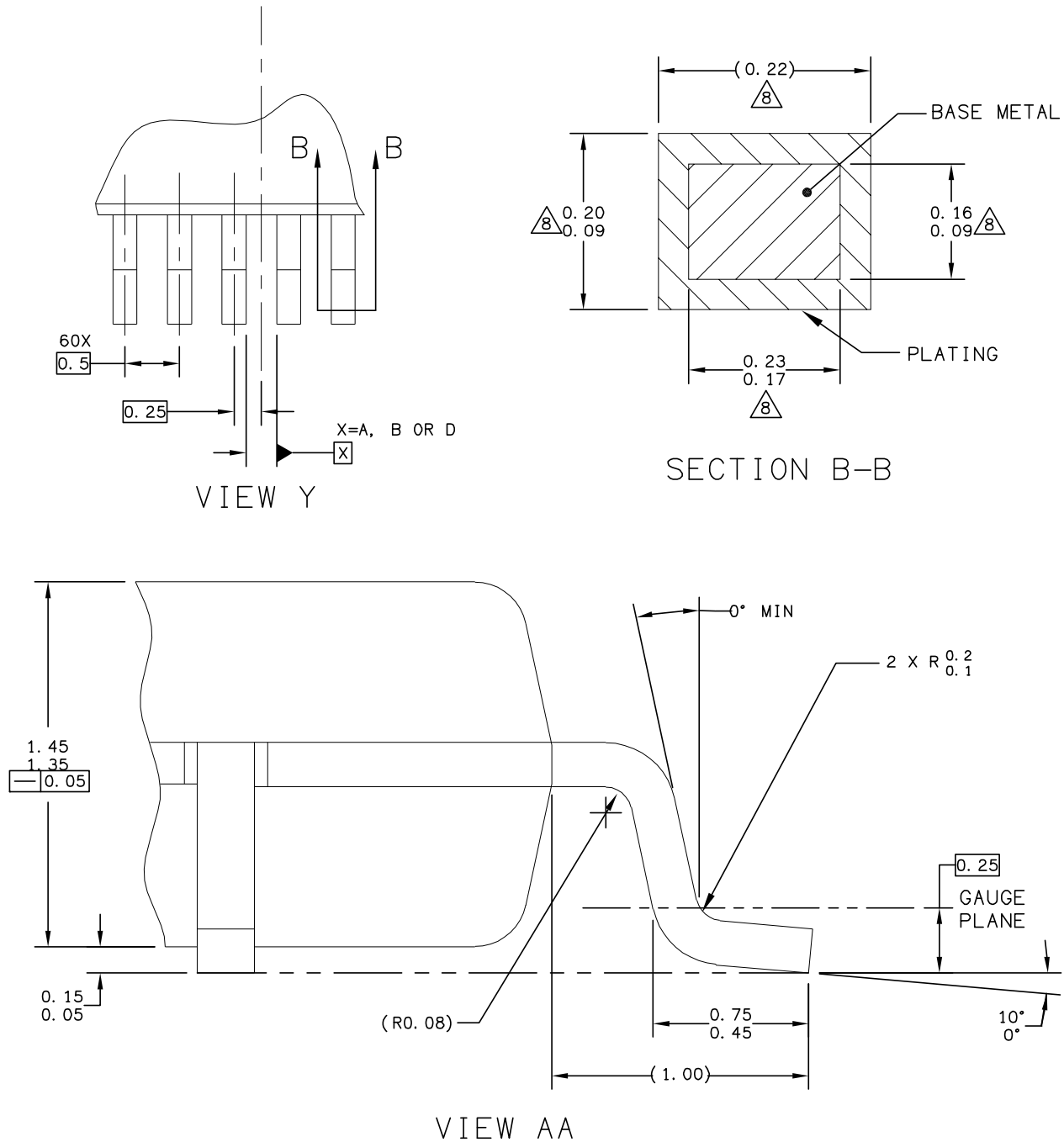
Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Conversion Time (Including sample time)	Short Sample (ADLSMP=0)	P	t_{ADC}	—	20	—	ADCK cycles	See the ADC chapter in the <i>MCF51QE128 Reference Manual</i> for conversion time variances
	Long Sample (ADLSMP=1)	C		—	40	—		
Sample Time	Short Sample (ADLSMP=0)	P	t_{ADS}	—	3.5	—	ADCK cycles	
	Long Sample (ADLSMP=1)	C		—	23.5	—		
Total Unadjusted Error	12 bit mode	T	E_{TUE}	—	±3.0	—	LSB ²	Includes Quantization
	10 bit mode	P		—	±1	±2.5		
	8 bit mode	T		—	±0.5	±1.0		
Differential Non-Linearity	12 bit mode	T	DNL	—	±1.75	—	LSB ²	
	10 bit mode ³	P		—	±0.5	±1.0		
	8 bit mode ³	T		—	±0.3	±0.5		
Integral Non-Linearity	12 bit mode	T	INL	—	±1.5	—	LSB ²	
	10 bit mode	T		—	±0.5	±1.0		
	8 bit mode	T		—	±0.3	±0.5		
Zero-Scale Error	12 bit mode	T	E_{ZS}	—	±1.5	—	LSB ²	$V_{ADIN} = V_{SSAD}$
	10 bit mode	P		—	±0.5	±1.5		
	8 bit mode	T		—	±0.5	±0.5		
Full-Scale Error	12 bit mode	T	E_{FS}	—	±1.0	—	LSB ²	$V_{ADIN} = V_{DDAD}$
	10 bit mode	P		—	±0.5	±1		
	8 bit mode	T		—	±0.5	±0.5		
Quantization Error	12 bit mode	D	E_Q	—	-1 to 0	—	LSB ²	
	10 bit mode			—	—	±0.5		
	8 bit mode			—	—	±0.5		
Input Leakage Error	12 bit mode	D	E_{IL}	—	±2	—	LSB ²	Pad leakage ⁴ * R_{AS}
	10 bit mode			—	±0.2	±4		
	8 bit mode			—	±0.1	±1.2		
Temp Sensor Slope	-40°C to 25°C	D	m	—	1.646	—	mV/°C	
	25°C to 85°C			—	1.769	—		
Temp Sensor Voltage	25°C	D	V_{TEMP25}	—	701.2	—	mV	

¹ Typical values assume $V_{DDAD} = 3.0V$, Temp = 25°C, $f_{ADCK} = 1.0MHz$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² 1 LSB = $(V_{REFH} - V_{REFL})/2^N$

³ Monotonicity and No-Missing-Codes guaranteed in 10 bit and 8 bit modes

⁴ Based on input pad leakage current. Refer to pad electricals.



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TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE		DOCUMENT NO: 98ASS23234W		REV: D	
		CASE NUMBER: 840F-02		06 APR 2005	
		STANDARD: JEDEC MS-026 BCD			

Figure 25. 64-pin LQFP Package Drawing (Case 840F, Doc #98ASS23234W), Sheet 2 of 3

- NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
 3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
 4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
 5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.
 6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
 7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
 8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.

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		CASE NUMBER: 840F-02		06 APR 2005	
		STANDARD: JEDEC MS-026 BCD			

Figure 26. 64-pin LQFP Package Drawing (Case 840F, Doc #98ASS23234W), Sheet 3 of 3

How to Reach Us:

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Freescale Semiconductor
Technical Information Center, EL516
2100 East Elliot Road
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Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
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+33 1 69 35 48 48 (French)
www.freescale.com/support

Japan:

Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor China Ltd.
Exchange Building 23F
No. 118 Jianguo Road
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Beijing 100022
China
+86 10 5879 8000
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